

## DMTH8008SPSQ

80V +175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

## **Product Summary**

BV <sub>DSS</sub>	RDS(ON) ID Tc = +25°	
80V	7.8mΩ @ V <sub>GS</sub> = 10V	92A

# **Description and Applications**

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- DC-DC converters
- Load switches

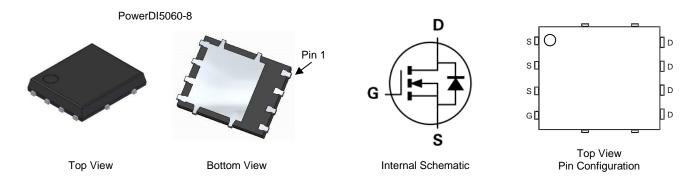
### Features

- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching (UIS) Test in Production Ensures More Reliable and Robust End Application
- High Conversion Efficiency
- Low RDS(ON) Minimizes On-State Losses
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMTH8008SPSQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

## **Mechanical Data**

- Package: PowerDI<sup>®</sup>5060-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.097 grams (Approximate)



## Ordering Information (Note 4)

Part Number	Paakaga	Packing		
Part Number	Package	Qty.	Carrier	
DMTH8008SPSQ-13	PowerDI5060-8	2,500	Tape & Reel	

Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

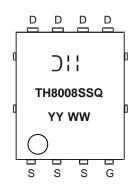
 See https://www.diodes.com/quality/lead-free/ for more information about Diodes incorporated sidelinitions of Halogen- and Antimony-free, Green and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



# **Marking Information**



) | | = Manufacturer's Marking TH8008SSQ = Product Type Marking Code YYWW = Date Code Marking YY = Year (ex: 24 = 2024) WW = Week (01 to 53)

# Maximum Ratings (@T<sub>C</sub> = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			VDSS	80	V
Gate-Source Voltage			Vgss	±20	V
Continuous Drain Current, V <sub>GS</sub> = 10V (Note 5)	lD	92 65	A		
Maximum Continuous Body Diode Forward Current (Note 5)			ls	83	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			Ідм	360	А
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)			lsм	360	А
Avalanche Current, L = 0.1mH (Note 6)			las	40	А
Avalanche Energy, L = 0.1mH (Note 6)			Eas	80	mJ

### Thermal Characteristics (@Tc = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 7)	T <sub>A</sub> = +25°C	PD	1.6	W
Thermal Resistance, Junction to Ambient (Note 7)	Steady State	Reja	92	°C/W
Total Power Dissipation (Note 8)	T <sub>A</sub> = +25°C	PD	3.4	W
Thermal Resistance, Junction to Ambient (Note 8)	Steady State	Reja	43	°C/W
Total Power Dissipation (Note 5)	Tc = +25°C	PD	100	W
Thermal Resistance, Junction to Case (Note 5)		Rejc	1.5	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

Notes: 5. Thermal resistance from junction to soldering point (on the exposed drain pad).

6.  $I_{AS}$  and  $E_{AS}$  ratings are based on low frequency and duty cycles to keep  $T_J = +25^{\circ}C$ .

7. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.

8. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.



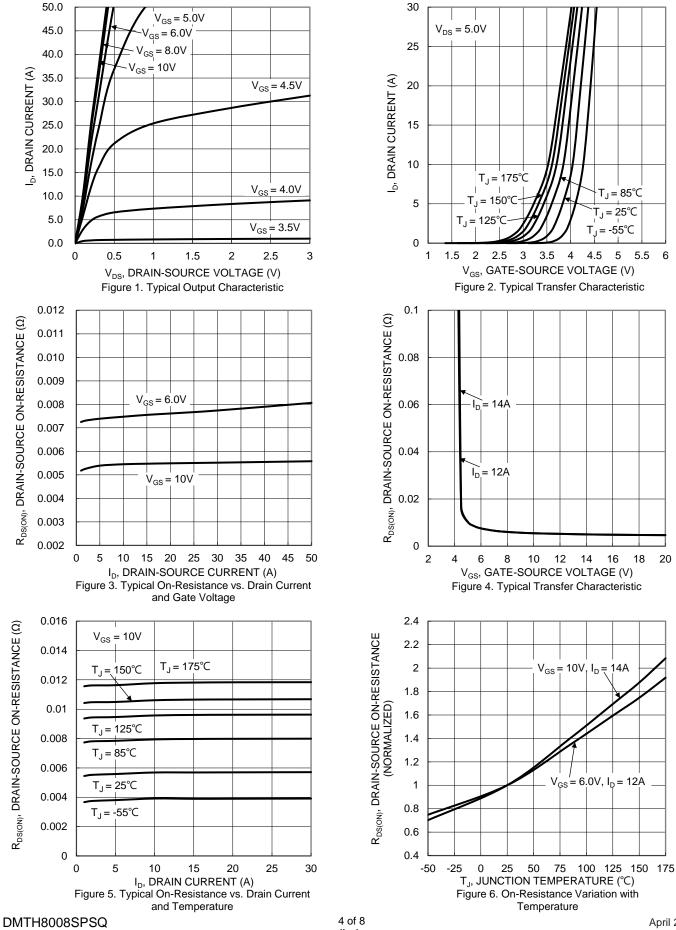
# Electrical Characteristics (@T<sub>C</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)							
Drain-Source Breakdown Voltage	BVDSS	80			V	$V_{GS} = 0V, I_D = 1mA$	
Zero Gate Voltage Drain Current	IDSS	_	_	1	μA	V <sub>DS</sub> = 64V, V <sub>GS</sub> = 0V	
Gate-Source Leakage	lgss		_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 9)							
Gate Threshold Voltage	Vgs(th)	2	_	4	V	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 1mA	
Static Drain-Source On-Resistance	Deserver	_	6.5	7.8	mΩ	$V_{GS} = 10V, I_D = 14A$	
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	_	7.8	11	1112	$V_{GS} = 6V, I_D = 12A$	
Diode Forward Voltage	Vsd	_	0.8	1.2	V	VGS = 0V, IS = 14A	
DYNAMIC CHARACTERISTICS (Note 10)							
Input Capacitance	Ciss	_	1950	_		$V_{DS} = 40V, V_{GS} = 0V$ f = 1MHz	
Output Capacitance	Coss		826	_	pF		
Reverse Transfer Capacitance	Crss	_	56	_			
Gate Resistance	Rg		1.7	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V <sub>GS</sub> = 6V)	Qg		23				
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg		34		nC	V <sub>DS</sub> = 40V, I <sub>D</sub> = 14A	
Gate-Source Charge	Qgs		6	_	nc		
Gate-Drain Charge	Q <sub>gd</sub>	_	12	_			
Turn-On Delay Time	td(on)	_	8	_			
Turn-On Rise Time	tR	_	15	_		$V_{DD} = 40V, V_{GS} = 10V$ I_D = 14A, Rg = 6Ω	
Turn-Off Delay Time	tD(OFF)	_	29	_	ns		
Turn-Off Fall Time	tF		21		]		
Body Diode Reverse Recovery Time	trr	_	43	_	ns		
Body Diode Reverse Recovery Charge	QRR	_	49	_	nC	Is = 14A, di/dt = 100A/µs	

Notes: 9. Short duration pulse test used to minimize self-heating effect. 10. Guaranteed by design. Not subject to product testing.



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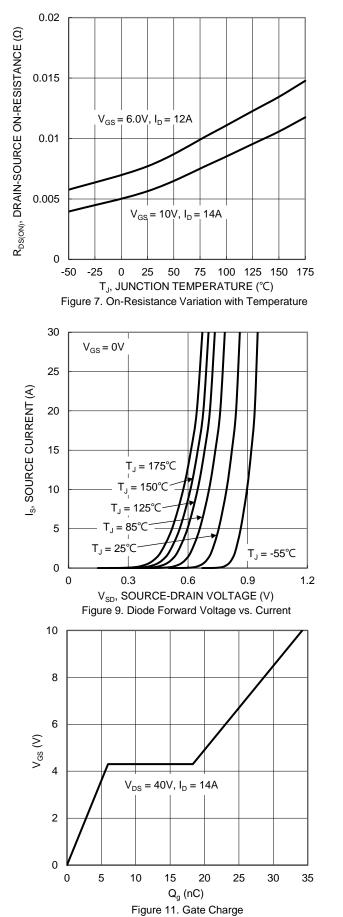
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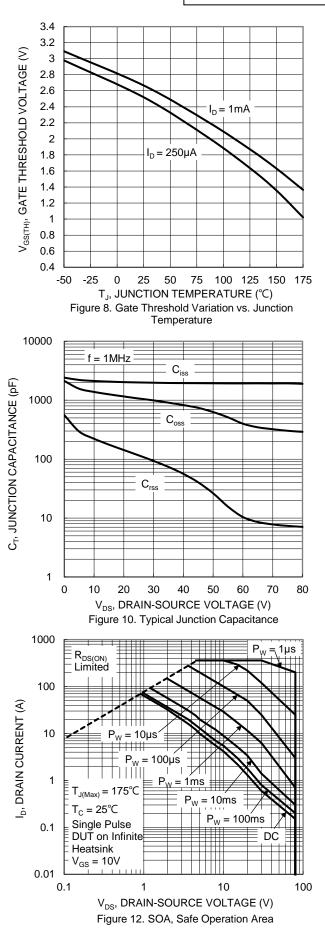
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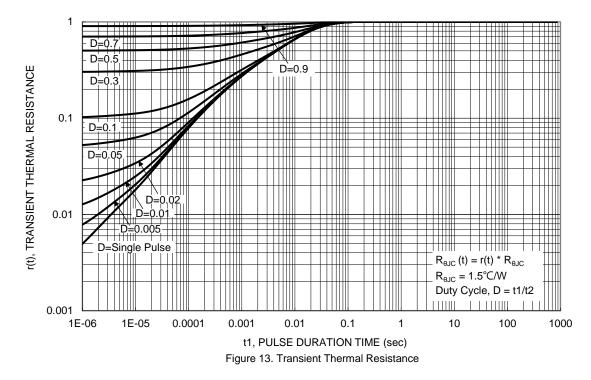




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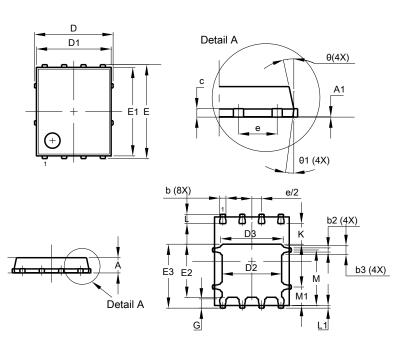




# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### PowerDI5060-8

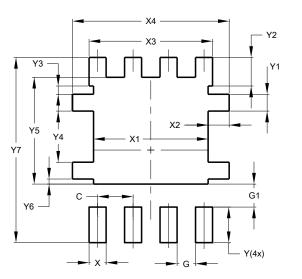


	PowerDI5060-8					
Dim	Min	Max	Тур			
Α	0.90	1.10	1.00			
A1	0.00	0.05	-			
b	0.33	0.51	0.41			
b2	0.200	0.350	0.273			
b3	0.40	0.80	0.60			
С	0.230	0.330	0.277			
D		5.15 BSC	;			
D1	4.70	5.10	4.90			
D2	3.70	4.10	3.90			
D3	3.90 4.30 4.10					
Е		6.15 BSC	;			
E1	5.60	6.00	5.80			
E2	3.28	3.68	3.48			
E3	3.99	4.39	4.19			
е	1.27 BSC					
G	0.51	0.71	0.61			
K	0.51	-	-			
L	0.51	0.71	0.61			
L1	0.100	0.200	0.175			
М	3.235	4.035	3.635			
M1	1.00	1.40	1.21			
Θ	10°	12°	11°			
Θ1	6°	8°	7°			
AI	All Dimensions in mm					

## Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

### PowerDI5060-8



Dimensions	Value (in mm)			
С	1.270			
G	0.660			
G1	0.820			
Х	0.610			
X1	4.100			
X2	0.755			
X3	4.420			
X4	5.610			
Y	1.270			
Y1	0.600			
Y2	1.020			
Y3	0.295			
Y4	1.825			
Y5	3.810			
Y6	0.180			
Y7	6.610			



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